# **Preliminary**

# High Temperature, Standard Frequency Oscillator



## **Features**

- 33 standard frequencies between 7.3728 MHz and 48 MHz
- 100% pin-to-pin drop-in replacement to quartz-based XO
- Excellent total frequency stability as low as ±25 PPM
- Industry best G-sensitivity of 0.1 PPB/G
- Low power consumption of 3.6 mA typical
- Standby mode for longer battery life
- LVCMOS/HCMOS compatible output
- Industry-standard packages: 2.0 x 1.6, 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- Pb-free, RoHS and REACH compliant
- Optional unique device ID for complete traceability (contact SiTime)
- Optional AECQ100 compliance (contact SiTime)

# **Applications**

- Automotive, medical, industrial and other high reliability electronics
- Infotainment systems, industrial sensors, collision detection devices, equipment control boards, etc.





(408) 328-4400

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# Electrical Characteristics<sup>[1, 2]</sup>

Parameter and Conditions	Symbol	Min.	Тур.	Max.	Unit	Condition
			F	requency R	ange	
Output Frequency Range	f	(Refer to ti	he frequency	list page 5)	MHz	33 standard frequencies between 7.3728 MHz and 75 MHz
	-		Freque	ncy Stability	and Aging	
Frequency Stability	F_stab	-25	-	+25	PPM	Inclusive of Initial tolerance at 25°C, and variations over
		-50	-	+50	PPM	operating temperature, rated power supply voltage and load.
Aging	Ag	-1.5	-	1.5	PPM	1st year at 25°C
			Operati	ng Tempera	ture Range	
Operating Temperature Range	T_use	-40	_	-105	°C	Extended Industrial
		-40	-	+125	°C	Automotive
		Sı	upply Voltag	ge and Curre	ent Consum	nption
Supply Voltage	Vdd	1.62	1.8	1.98	V	Contact SiTime for 1.5V support
		2.25	2.5	2.75	V	
		2.52	2.8	3.08	V	
		2.7	3.0	3.3	V	
		2.97	3.3	3.63	V	
		2.25	-	3.63	V	
Current Consumption	ldd	-	3.9	5	mA	No load condition, f = 20 MHz, Vdd = 2.5V, 2.8V, 3.0V or 3.3V
		-	3.6	4.5	mA	No load condition, f = 20 MHz, Vdd = 1.8V
Standby Current	I_std	-	2.5	10	μΑ	ST = GND, Vdd = 3.0V or 3.3V, Output is Weakly Pulled Down
		-	2.5	10	μΑ	ST = GND, Vdd = 2.5V or 2.8V, Output is Weakly Pulled Down
		-	1	5	μΑ	ST = GND, Vdd = 1.8V, Output is Weakly Pulled Down
			LVCMOS	Output Ch	aracteristic	S
Duty Cycle	DC	45	-	55	%	All Vdds
Rise/Fall Time	Tr, Tf	-	1.2	2.5	ns	Vdd = 2.5V, 2.8V, 3.0V or 3.3V, 20% - 80%
		-	1.5	3.5	ns	Vdd =1.8V, 20% - 80%
		-	1.5	3	ns	Vdd = 2.25V - 3.63V, 20% - 80%
Output High Voltage	VOH	90%	_	_	Vdd	IOH = -4 mA (Vdd = 3.0V or 3.3V) IOH = -3 mA (Vdd = 2.8V and Vdd = 2.5V) IOH = -2 mA (Vdd = 1.8V)
Output Low Voltage	VOL	-	_	10%	Vdd	IOL = 4 mA (Vdd = 3.0V or 3.3V) IOL = 3 mA (Vdd = 2.8V and Vdd = 2.5V) IOL = 2 mA (Vdd = 1.8V)
	1		Inp	ut Characte	ristics	1
Input High Voltage	VIH	70%	_	_	Vdd	Pin 1, OE or ST
Input Low Voltage	VIL	_	_	30%	Vdd	Pin 1, OE or ST
Input Pull-up Impedence	Z_in	_	100	250	kΩ	Pin 1, OE logic high or logic low, or ST logic high
		2	-	-	ΜΩ	Pin 1, ST logic low

#### Note:

SiTime Corporation

2. Contact SiTime for custom drive strength to drive higher or multiple load, or SoftEdge™ option for EMI reduction.

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Rev. 0.92 Revised January 16, 2013

<sup>1.</sup> All electrical specifications in the above table are specified with 15 pF output load and for all Vdd(s) unless otherwise stated.

# **High Temperature, Standard Frequency Oscillator**



# Electrical Characteristics<sup>[1, 2]</sup>(continued)

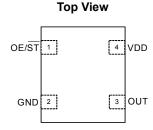
Parameter and Conditions	Symbol	Min.	Тур.	Max.	Unit	Condition		
			Startu	and Resur	ne Timing			
Startup Time	T_start	-	-	5	ms	Measured from the time Vdd reaches its rated minimum value		
Enable/Disable Time	T_oe	-	-	150	ns			
Resume Time	T_resume	-	-	5	ms	Measured from the time ST pin crosses 50% threshold		
				Jitter				
RMS Period Jitter	T_jitt	-	2	4	ps	f = 20 MHz, Vdd = 2.5V, 2.8V, 3.0V or 3.3V		
		-	2	4.5	ps	f = 20 MHz, Vdd = 1.8V		
RMS Phase Jitter (random)	T_phj	-	0.7	1	ps	Integration bandwidth = 900 kHz to 7.5 MHz		
		_	1.5	3	ps	Integration bandwidth = 12 kHz to 20 MHz		

#### Notes:

- 1. All electrical specifications in the above table are specified with 15 pF output load and for all Vdd(s) unless otherwise stated.
- 2. Contact SiTime for custom drive strength to drive higher or multiple load, or SoftEdge™ option for EMI reduction.

# **Pin Description**

Pin	Symbol		Functionality
		Output Enable	H or Open <sup>[3]</sup> : specified frequency output L: output is high impedance. Only output driver is disabled.
1	1 OE/ ST Stand		H or Open <sup>[3]</sup> : specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std.
2	GND	Power	Electrical ground <sup>[4]</sup>
3	OUT	Output	Oscillator output
4	VDD	Power	Power supply voltage <sup>[4]</sup>



#### Notes:

- 3. A pull-up resistor of <10 k $\Omega$  between OE/  $\overline{ST}$  pin and Vdd is recommended in high noise environment.
- 4. A capacitor value of 0.1  $\mu F$  between Vdd and GND is recommended.

# **Absolute Maximum**

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge	-	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	°C
Junction Temperature	_	150	°C

# **Thermal Consideration**

Package	θJA, 4 Layer Board °C/W)	θJA, 2 Layer Board (°C/W)	θJC, Bottom (°C/W)
7050	191	263	30
5032	97	199	24
3225	109	212	27
2520	117	222	26
2016	124	227	26

# **Environmental Compliance**

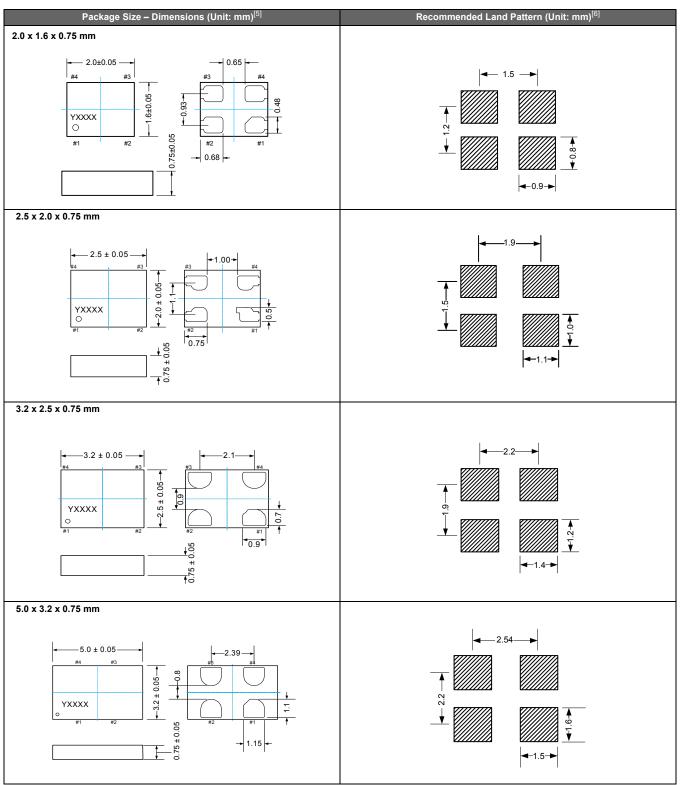
•			
Parameter	Condition/Test Method		
Mechanical Shock	MIL-STD-883F, Method 2002		
Mechanical Vibration	MIL-STD-883F, Method 2007		
Temperature Cycle	JESD22, Method A104		
Solderability	MIL-STD-883F, Method 2003		
Moisture Sensitivity Level	MSL1 @ 260°C		

# SiT1618

# **High Temperature, Standard Frequency Oscillator**



# **Dimensions and Patterns**



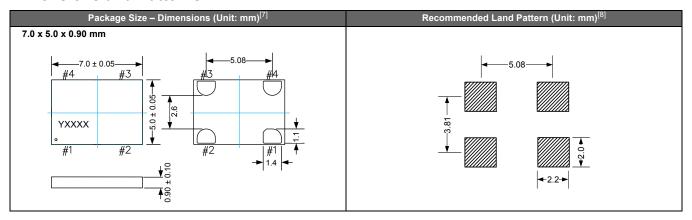
- 5. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
  6. A capacitor of value 0.1 µF between Vdd and GND is recommended.

# SiT1618

# **High Temperature, Standard Frequency Oscillator**



# **Dimensions and Patterns**



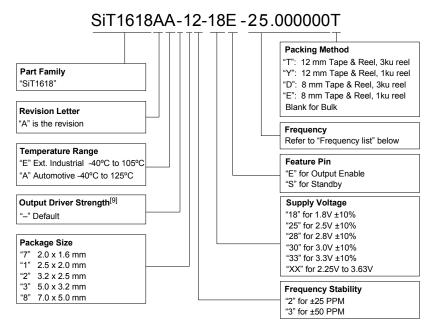
## Notes:

- 7. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.

  8. A capacitor of value 0.1 µF between Vdd and GND is recommended.



# **Ordering Information**



#### Note:

9. Contact SiTime for custom drive strength to drive higher or multiple load, or SoftEdge™ option for EMI reduction.

# Supported Frequencies<sup>[10]</sup>

7.3728 MHz	8 MHz	8.192 MHz	9.8304 MHz	9.84375 MHz	11.0592 MHz	12 MHz	12.288 MHz	13 MHz
13.225625 MHz	13.52127 MHz	14.31818 MHz	14.7456 MHz	15 MHz	16 MHz	16.384 MHz	18.432 MHz	19.6608 MHz
20 MHz	22.1184 MHz	24 MHz	24.56 MHz	24.576 MHz	25 MHz	26 MHz	27 MHz	29.4912 MHz
30 MHz	32 MHz	33 MHz	36 MHz	40 MHz	48 MHz			

#### Note:

10. Contact SiTime or refer to SiT8918 datasheet for frequencies that are not listed in the above table.

# Ordering Codes for Supported Tape & Reel Packing Method[11]

Device Size	12 mm T&R (3ku)	12 mm T&R (1ku)	8 mm T&R (3ku)	8 mm T&R (1ku)
2.0 x 1.6 mm	-	-	D	E
2.5 x 2.0 mm	-	-	D	E
3.2 x 2.5 mm	-	-	D	E
5.0 x 3.2 mm	Т	Y	-	-
7.0 x 5.0 mm	Т	Y	_	_

#### Note:

11. For "-", contact SiTime for availability.

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# **Supplemental Information**

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# Silicon MEMS Outperforms Quartz

# Silicon MEMS Outperforms Quartz



## **Best Reliability**

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, SiTime has in-house MEMS and analog CMOS expertise, which allows SiTime to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

## Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced Epi-Seal™ process, which eliminates foreign particles and improves long term aging and reliability
- · World-class MEMS and CMOS design expertise

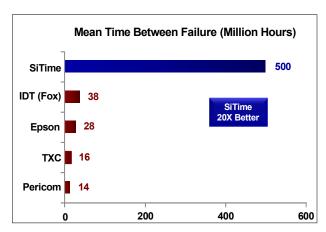


Figure 1. Reliability Comparison<sup>[1]</sup>

#### **Best Aging**

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new SiTime product specifies 10-year aging. A comparison is shown in Figure 2.

# Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced Epi-Seal™ process, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

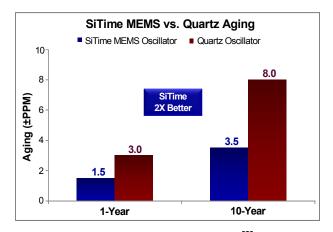


Figure 2. Aging Comparison<sup>[2]</sup>

## Best Electro Magnetic Susceptibility (EMS)

SiTime's oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

## Why is SiTime Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS

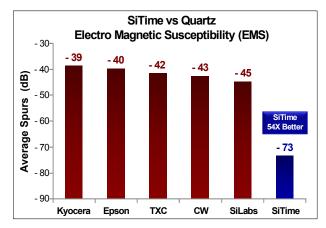


Figure 3. Electro Magnetic Susceptibility (EMS)[3]

## **Best Power Supply Noise Rejection**

SiTime's MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

## Why is SiTime Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- · Best analog CMOS design expertise

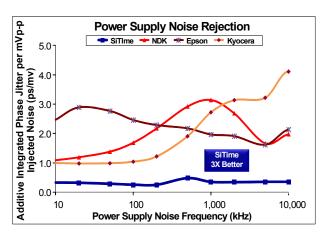


Figure 4. Power Supply Noise Rejection<sup>[4]</sup>

# Silicon MEMS Outperforms Quartz



## **Best Vibration Robustness**

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

## Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than guartz
- Center-anchored MEMS resonator is the most robust design

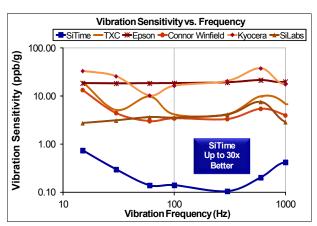


Figure 5. Vibration Robustness<sup>[5]</sup>

#### Notes:

- 1. Data Source: Reliability documents of named companies.
- 2. Data source: SiTime and quartz oscillator devices datasheets.
- 3. Test conditions for Electro Magnetic Susceptibility (EMS):
  - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
  - Field strength: 3V/m
  - Radiated signal modulation: AM 1 kHz at 80% depth
  - Carrier frequency scan: 80 MHz 1 GHz in 1% steps
  - · Antenna polarization: Vertical
  - DUT position: Center aligned to antenna

## Devices used in this test:

SiTime, SiT9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz

Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz

TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz

Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz

Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz

SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz

4. 50 mV pk-pk Sinusoidal voltage.

#### Devices used in this test:

SiTime, SiT8208AI-33-33E-25.000000, MEMS based - 25 MHz

NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz

Kyocera, KC2016B25M0C1GE00 - quartz based - 25 MHz

Epson, SG-310SCF-25M0-MB3 - quartz based - 25 MHz

- 5. Devices used in this test: same as EMS test stated in Note 3.
- 6. Test conditions for shock test:
  - MIL-STD-883F Method 2002
  - Condition A: half sine wave shock pulse, 500-g, 1ms
  - $\bullet$  Continuous frequency measurement in 100  $\mu s$  gate time for 10 seconds

Devices used in this test: same as EMS test stated in Note 3

7. Additional data, including setup and detailed results, is available upon request to qualified customers. Please contact productsupport@sitime.com.

## **Best Shock Robustness**

SiTime's oscillators can withstand at least  $50,000\ g$  shock. They all maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

## Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than guartz
- Center-anchored MEMS resonator is the most robust design

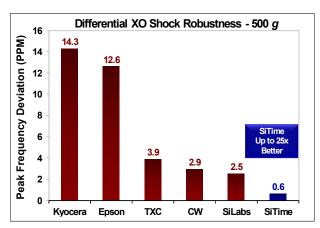


Figure 6. Shock Robustness<sup>[6]</sup>

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